

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

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MS1512

RF & MICROWAVE TRANSISTORS UHF TV/LINEAR APPLICATIONS

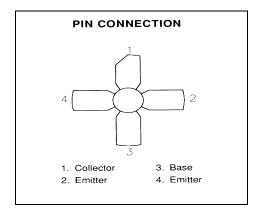
Features

- 860 MHz
- 20 VOLTS
- CLASS A LINEAR OPERATION
- **P**_{OUT} = 1.0 WATT
- $G_P = 10.0 \text{ dB MINIMUM}$
- COMMON EMITTER CONFIGURATION

.280 4L STUD (M122) epoxy sealed

DESCRIPTION:

The MS1512 is a silicon NPN bipolar transistor designed for UHF linear applications, specifically TV Bands IV and V. The MS1512 is characterized for high linearity, Class A operation. Device ruggedness and reliability are maximized with emitter ballasting and gold metallization.



ABSOLUTEMAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit	
V _{CBO}	Collector-Base Voltage	45	V	
V _{CEO}	Collector-Emitter Voltage	25	V	
V _{EBO}	Emitter-Base Voltage	3.5	V	
Ic	Device Current	1.2	Α	
P _{DISS}	Power Dissipation	19.4	W	
T J	Junction Temperature	+200	°C	
T _{STG}	Storage Temperature	-65 to +150	°C	

Thermal Data

$R_{TH(J-C)}$	Junction-case Thermal Resistance	9.0	°C/W
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MS1512

ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

Symbol				Value		Unit
Syllibol			Min.	Typ.		Oilit
BV _{CBO}	Ic	I _E	45			V
BV _c	I = 40mA	R_{BE} Ω	50			V
CEO	c = 40 mA	_B =0 mA	24			V
EBO	_E = .5 mA	_c = 0 mA	3.5			V
СВО	_{CB} = 28 V	I = 0 mA			0.45	
h	V = 5 V	I = 200 mA			120	-

DYNAMIC

Symbol	Test Conditions						
Syllibol		rest Conditions			Typ.	Max.	
P	f = 860 MHz	P _{IN}	_{CE} = 20V	1.0			W
P		P = 100mW	V _{CE}	10			dB
IMD ₃	P _{SYNC}	_{CE} = 20V	_C = 440 mA			-	dBc
Сов	f = 1 MHz	V _{CB}					pf

Conditions: V_{CE} $_{C}$ = 440 mA Conditions: f_1 -8dBc), f =863.5MHz(-

3=864.5MHz(7dBc)

IMPEDANCE DATA

FRE	Z (Ω)	$_{ t CL}(\Omega)$
470 MHz	2.0 - j 1.5	23 - j 35
650 MHz	1.9 - j 0.5	15 - j 27
860 MHz	1.8 + j 0.8	8.0 - j 15



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PACKAGE MECHANI CAL DATA

